

PNP MEDIUM POWER TRANSISTORS

Type	Marking
STF817	817
STN817	N817

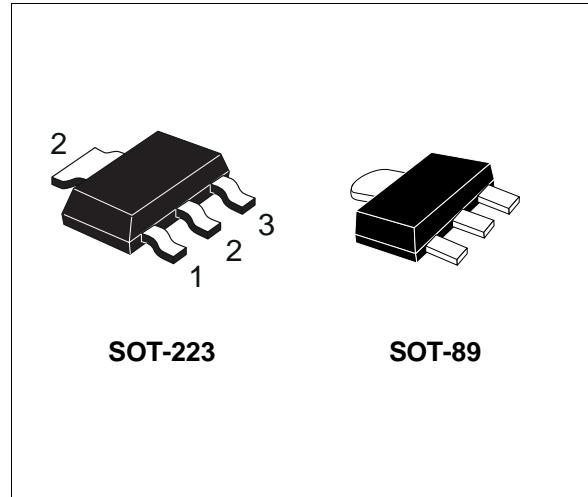
- SURFACE-MOUNTING DEVICES IN MEDIUM POWER SOT-223 AND SOT-89 PACKAGES
- AVAILABLE IN TAPE & REEL PACKING

APPLICATIONS

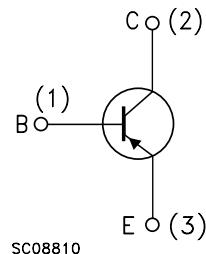
- VOLTAGE REGULATION
- RELAY DRIVER
- GENERIC SWITCH

DESCRIPTION

The STF817 and STN817 are PNP transistors manufactured using Planar Technology resulting in rugged high performance devices.



INTERNAL SCHEMATIC DIAGRAM



SC08810

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value		Unit
		Devices	STN817	
		Packages	SOT-223	
V_{CBO}	Collector-Base Voltage ($I_E = 0$)		-120	V
V_{CEO}	Collector-Emitter Voltage ($I_B = 0$)		-80	V
V_{EBO}	Emitter-Base Voltage ($I_C = 0$)		-5	V
I_C	Collector Current		-1.5	A
I_{CM}	Collector Peak Current ($t_p < 5 \text{ ms}$)		-2	A
I_B	Base Current		-0.3	A
I_{BM}	Base Peak Current ($t_p < 5 \text{ ms}$)		-0.6	A
P_{tot}	Total Dissipation at $T_c = 25^\circ\text{C}$	1.6	1.4	W
T_{stg}	Storage Temperature	-65 to 150		$^\circ\text{C}$
T_j	Max. Operating Junction Temperature	150		$^\circ\text{C}$

STF817 - STN817

THERMAL DATA

		SOT-223	SOT-89	
$R_{\text{thj-amb}}$ •	Thermal Resistance Junction-ambient	Max	78	89 °C/W

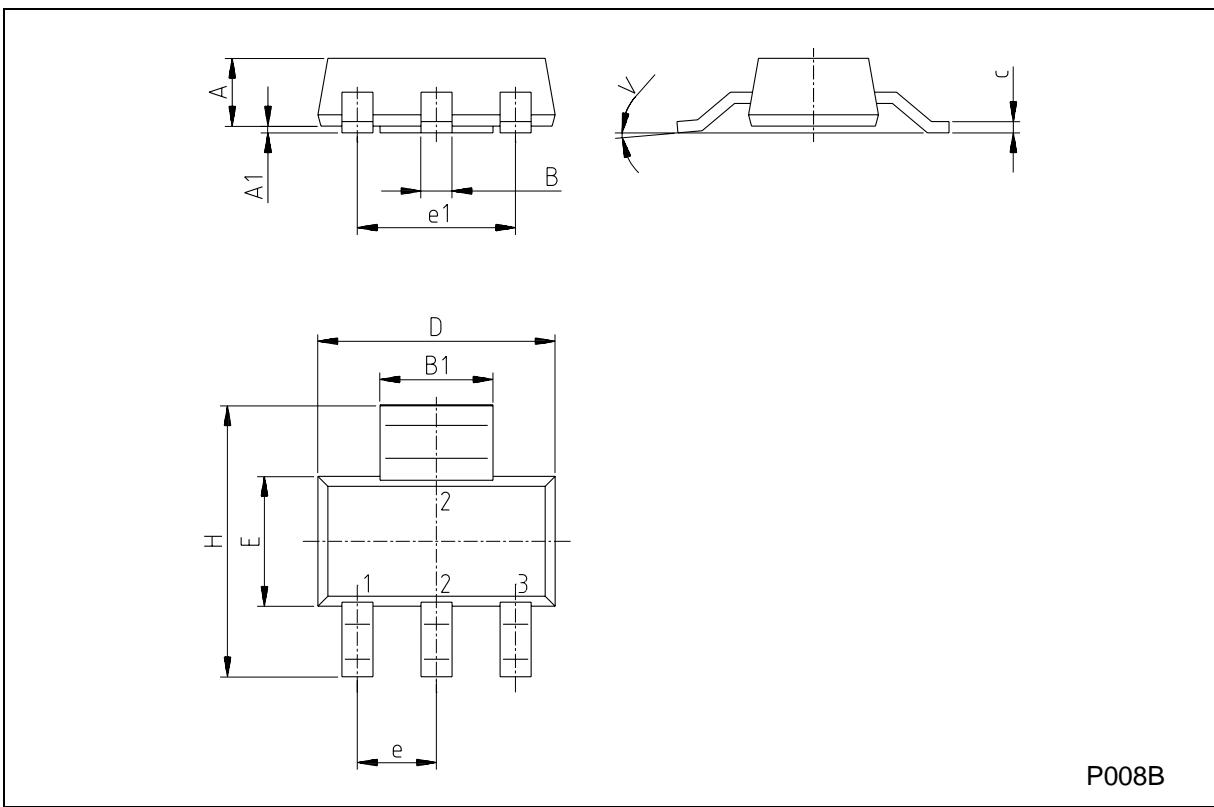
• Device mounted on a PCB area of 1 cm².

ELECTRICAL CHARACTERISTICS ($T_{\text{case}} = 25^{\circ}\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{CES}	Collector Cut-off Current ($V_{\text{BE}} = 0$)	$V_{\text{CE}} = -120 \text{ V}$			-500	μA
I_{CEO}	Collector Cut-off Current ($I_B = 0$)	$V_{\text{CE}} = -80 \text{ V}$			-1	mA
I_{EBO}	Emitter Cut-off Current ($I_C = 0$)	$V_{\text{EB}} = -5 \text{ V}$			-100	μA
$V_{\text{CEO(sus)}}^*$	Collector-Emitter Sustaining Voltage ($I_B = 0$)	$I_C = -10 \text{ mA}$	-80			V
$V_{\text{CE(sat)}}^*$	Collector-Emitter Saturation Voltage	$I_C = -100 \text{ mA}$ $I_C = -1 \text{ A}$	$I_B = -10 \text{ mA}$ $I_B = -100 \text{ mA}$		-0.25 -0.5	V
$V_{\text{BE(sat)}}^*$	Base-Emitter Saturation Voltage	$I_C = -100 \text{ mA}$ $I_C = -1 \text{ A}$	$I_B = -10 \text{ mA}$ $I_B = -100 \text{ mA}$		-1 -1.1	V
h_{FE}^*	DC Current Gain	$I_C = -100 \text{ mA}$ $I_C = -500 \text{ mA}$ $I_C = -1 \text{ A}$	$V_{\text{CE}} = -2 \text{ V}$ $V_{\text{CE}} = -2 \text{ V}$ $V_{\text{CE}} = -2 \text{ V}$	140 80 40		
f_T	Transition Frequency	$I_C = -0.1 \text{ A}$	$V_{\text{CE}} = -10 \text{ V}$	50		MHz

* Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %

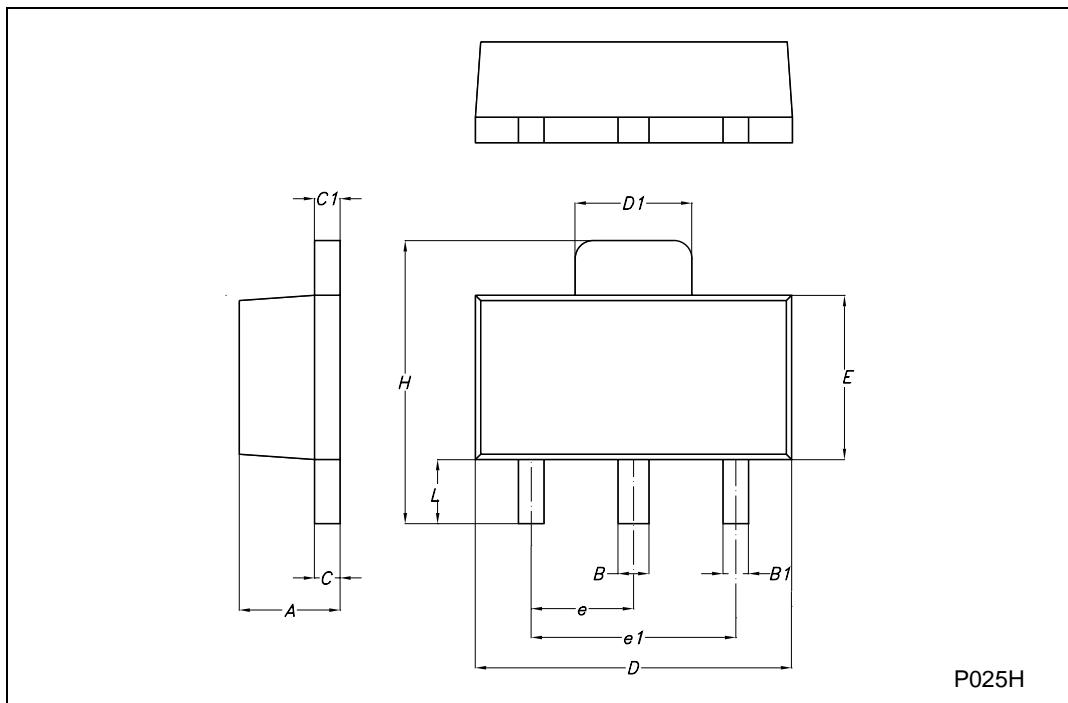
SOT-223 MECHANICAL DATA						
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.80			0.071
B	0.60	0.70	0.80	0.024	0.027	0.031
B1	2.90	3.00	3.10	0.114	0.118	0.122
c	0.24	0.26	0.32	0.009	0.010	0.013
D	6.30	6.50	6.70	0.248	0.256	0.264
e		2.30			0.090	
e1		4.60			0.181	
E	3.30	3.50	3.70	0.130	0.138	0.146
H	6.70	7.00	7.30	0.264	0.276	0.287
V			10°			10°
A1		0.02				



P008B

SOT-89 MECHANICAL DATA

DIM.	mm			mils		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	1.4		1.6	55.1		63.0
B	0.44		0.56	17.3		22.0
B1	0.36		0.48	14.2		18.9
C	0.35		0.44	13.8		17.3
C1	0.35		0.44	13.8		17.3
D	4.4		4.6	173.2		181.1
D1	1.62		1.83	63.8		72.0
E	2.29		2.6	90.2		102.4
e	1.42		1.57	55.9		61.8
e1	2.92		3.07	115.0		120.9
H	3.94		4.25	155.1		167.3
L	0.89		1.2	35.0		47.2



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